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STMicroelectronics
BULT3P3

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BULT3P3

Medium voltage fast-switching PNP power transistor

Features

- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Application

■ Electronic ballast for fluorescent lighting

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and medium voltage capability.

It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

The device is expressly designed for a new solution to be used in compact fluorescent lamps, where it is coupled with the BULT3N4, its complementary NPN transistor.

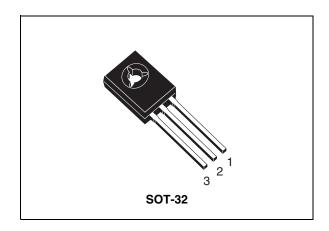


Figure 1. Internal schematic diagram

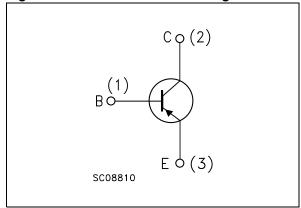


Table 1. Device summary

Order code	Marking	Package	Packing
BULT3P3	BULT3P3	SOT-32	Tube

September 2009 Doc ID 16300 Rev 1 1/8



Electrical ratings BULT3P3

1 Electrical ratings

Table 2. Absolute maximum ratings

	7.000.000		
Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	-300	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-200	V
V _{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = -1.5$ A, $t_p < 100$ μ s, $T_J < 150$ °C)	V _{(BR)EBO}	V
I _C	Collector current	-3	Α
I _{CM}	Collector peak current (t _P < 5 ms)	-6	Α
I _B	Base current	-1.5	Α
I _{BM}	Base peak current (t _P < 5 ms)	-3	Α
P _{TOT}	Total dissipation at T _c = 25 °C	32	W
T _{STG} Storage temperature		-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance junction-case max	3.9	°C/W





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Electrical characteristics

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current	V _{CE} = - 300 V			-0.1	mA
OLO	(V _{BE} = 0)	$V_{CE} = -300 \text{ V}$ $T_{C} = 125 ^{\circ}\text{C}$			-0.5	mA
V _{(BR)EBO}	Emitter-base breakdown voltage $(I_C = 0)$	I _E = - 10 mA	-6		-12	V
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C = - 10 mA	-200			V
V (1)	Collector-emitter	$I_C = -0.7 \text{ A}$ $I_B = -0.1 \text{ A}$			-0.5	V
V _{CE(sat)} (1)	saturation voltage	$I_C = -1 A$ $I_B = -0.2 A$			-0.5	V
	Dana amaittan aatuwatian	$I_C = -0.5 \text{ A}$ $I_B = -0.1 \text{ A}$			-1.0	V
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = -1 A$ $I_B = -0.2 A$			-1.1	V
		$I_C = -2 A$ $I_B = -0.4 A$			-1.3	V
		$I_C = -10 \text{mA}$ $V_{CE} = -5 \text{ V}$	10			
h _{FE}	DC current gain	$I_C = -0.75 \text{ A} V_{CE} = -5 \text{ V}$	22	28	36	
		$I_C = -2 A$ $V_{CE} = -5 V$	4			
	Resistive load	$I_{\rm C} = -0.7 \text{A} \text{V}_{\rm CC} = -150 \text{V}$		60		ns
t _r	Rise time	$I_{B(on)} = -I_{B(off)} = 140 \text{ mA}$		1.2	1.6	μs
t _s	Storage time	$T_p = 30 \mu s$		70	100	ns
t _f	Fall time	1ρ – 00 μ3		70	100	113
	Inductive load	$I_C = -1 \text{ A}$ $I_{B(on)} = 100 \text{ mA}$				
t _s	Storage time	$V_{BE(off)} = 5 \text{ V}$ $R_{bb} = 0$		110	180	ns
t _f	Fall time	V _{clamp} = 150 V L = 1 mH		35	70	ns

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %

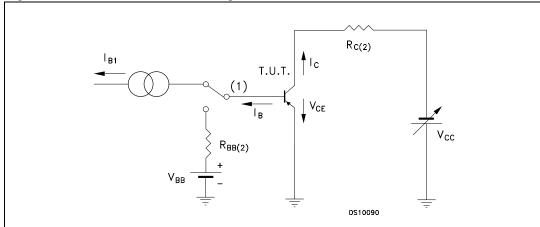


Electrical characteristics

BULT3P3

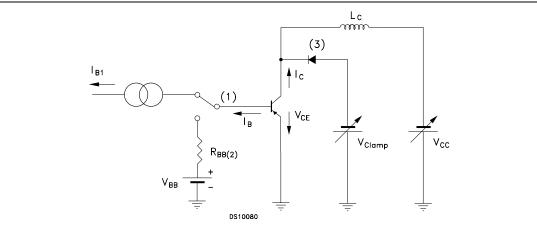
2.1 Test circuits

Figure 2. Resistive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor

Figure 3. Inductive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier





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Datasheet of BULT3P3 - TRANS PNP 200V 3A SOT32

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Package mechanical data

3 Package mechanical data

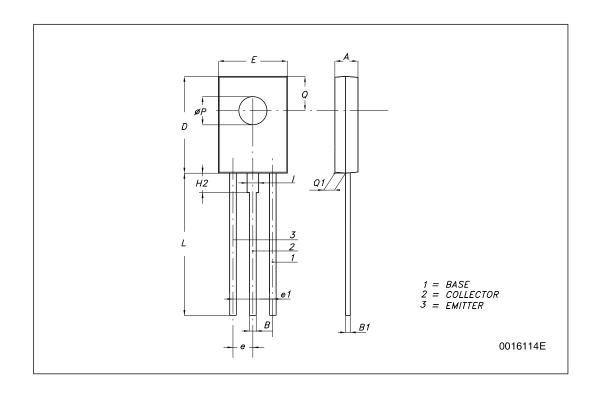
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Package mechanical data

BULT3P3

DIM.		mm.				
DIN.	MIN.	TYP	MAX.			
А	2.4		2.9			
В	0.64		0.88			
B1	0.39		0.63			
D	10.5		11.05			
E	7.4		7.8			
е	2.04	2.29	2.54			
e1	4.07 4.58		5.08			
L	15.3		16			
Р	2.9		3.2			
Q		3.8				
Q1	1		1.52			
H2		2.15				
I		1.27				





BULT3P3 Revision history

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
25-Sep-2009	1	Initial release





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